	φ	ω	7 0	n (л ,) 4	W	2 +	L Number
	10	172	11	ນ ຖ ນ	ا ح	N (o.	N 1	Hits 2
	same carbide same	same carbide same key	(silicon same molten same cvd) and infiltration		ilion same infiltration	same molton same cvd	silicon same infiltration same molton same cvd	gb-2022490-\$.did.	Search Text
US-PGPUB; EPO; JPO; DERWENT; IBM TDB	US-PGPUB; EPO; JPO; DERWENT; IBM TDB USPAT;	US-PGPUB; EPO; JPO; DERWENT; IBM TDB USPAT;	US-PGPUB; EPO; JPO; DERWENT; IBM IDB USPAT;	US-PGPUB; EPO; JPO; DERWENT; IBM TDB	US-PGPUB; EPO; JPO; DERWENT; IBM TDB USPAT;	US-PGPUB; EPO; JPO; DERWENT; IBM_TDB USPAT;	US-PGPUB; EPO; JPO; DERWENT; IBM_TDB USPAT;	US-PGPUB; EPO; JPO; DERWENT; IBM TDB USPAT;	DB USPAT;
	2004/03/26 15:36	2004/03/26 15:36	15:3	15: ₂	2004/03/26 15:23	2004/03/26 15:26	2004/03/26 15:23	ր Ω	Time stamp 2004/03/26 15:14

L Number	Hits	Search Text	DB
1	18	US-4070197-\$.DID. OR US-4238540-\$.DID. OR US-4592268-\$.DID. OR	USPAT;
		US-4608318-\$.DID. OR US-4621001-\$.DID. OR US-4921554-\$.DID. OR	US-PGPUB;
		US-5526867-\$.DID. OR US-5585190-\$.DID. OR US-6162019-\$.DID.	EPO; JPO;
			DERWENT;
			IBM TDB
ω	2292	silicon adj carbide and (join or joined or joining) and adhesive	USPAT;
			US-PGPUB;
			EPO; JPO;
			DERWENT;
			IBM TDB
4	284	(silicon adj carbide and (join or joined or joining) and adhesive) and	USPAT;
		(infiltrate or infiltrant or infiltrating or infiltration or infiltrated)	US-PGPUB;
			EPO; JPO;
			DERWENT;
			IBM TDB
G	47	((silicon adj carbide and (join or joined or joining) and adhesive) and	USPAT;
		(infiltrate or infiltrant or infiltrating or infiltration or infiltrated))	US-PGPUB;
		and (key or keyed or keying)	EPO; JPO;
			DERWENT;
			IBM TDB